

- Ideal for European 315.0 MHz Transmitters
- Very Low Series Resistance
- Quartz Stability
- Surface-Mount Ceramic Case
- Complies with Directive 2002/95/EC (RoHS)



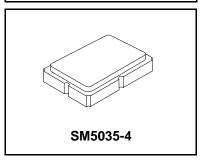
The RO3073A-1 is a true one-port, surface-acoustic-wave (SAW) resonator in a surface-mount, ceramic case. It provides reliable, fundamental-mode, quartz frequency stabilization of fixed-frequency transmitters operating at 315.0 MHz. This SAW is designed specifically for remote-control and wireless security transmitters operating in Europe under ETSI I-ETS 300 220 and in Germany under FTZ 17 TR 2100.

Absolute Maximum Ratings

Rating	Value	Units	
CW RF Power Dissipation (See: Typical Test Circuit)	+0	dBm	
DC voltage Between Terminals (Observe ESD Precautions)	±30	VDC	
Case Temperature	-40 to +85	°C	
Soldering Temperature (10 seconds / 5 cycles max.)	260	°C	

RO3073A-1

315.0 MHz SAW Resonator



Electrical Characteristics

Characteristic		Sym	Notes	Minimum	Typical	Maximum	Units
Center Frequency (+25 °C)	Absolute Frequency	f _C	2245	314.950		315.050	MHz
	Tolerance from 315.0 MHz	Δf_{C}	2,3,4,5			±50	kHz
Insertion Loss	Insertion Loss		2,5,6		1.5	2.2	dB
Quality Factor	Unloaded Q	Q _U	5,6,7		8000		
	50 Ω Loaded Q	Q_L			1300		
Temperature Stability	Turnover Temperature	T _O		10	25	40	°C
	Turnover Frequency	f _O	6,7,8		f _C		
	Frequency Temperature Coefficient	FTC			0.032		ppm/°C ²
Frequency Aging	Absolute Value during the First Year	f _A	1		≤10		ppm/yr
DC Insulation Resistance between Any Two Terminals			5	1.0			MΩ
RF Equivalent RLC Model	Motional Resistance	R_{M}	5, 7, 9		19.4		Ω
	Motional Inductance	L _M			78.4		μH
	Motional Capacitance	C _M			3.3		fF
	Shunt Static Capacitance	Co	5, 6, 9		4.1		pF
Test Fixture Shunt Inductance		L _{TEST}	2, 7		64.2		nH
Lid Symbolization (in addition to Lot and/or Date Codes)		742 // YWWS					

CAUTION: Electrostatic Sensitive Device. Observe precautions for handling. Notes:

- Frequency aging is the change in f_C with time and is specified at +65°C or less.
 Aging may exceed the specification for prolonged temperatures above +65°C.
 Typically, aging is greatest the first year after manufacture, decreasing in subsequent years.
- 2. The center frequency, f_C , is measured at the minimum insertion loss point, IL_{MIN} , with the resonator in the 50 Ω test system (VSWR \leq 1.2:1). The shunt inductance, L_{TEST} , is tuned for parallel resonance with C_O at f_C . Typically, $f_{OS-CILLATOR}$ or $f_{TRANSMITTER}$ is approximately equal to the resonator f_C .
- One or more of the following United States patents apply: 4,454,488 and 4,616,197.
- Typically, equipment utilizing this device requires emissions testing and government approval, which is the responsibility of the equipment manufacturer.
- 5. Unless noted otherwise, case temperature $T_C = +25^{\circ}C \pm 2^{\circ}C$.
- 6. The design, manufacturing process, and specifications of this device are subject to change without notice.
- Derived mathematically from one or more of the following directly measured parameters: f_C, IL, 3 dB bandwidth, f_C versus T_C, and C_O.

- Turnover temperature, T_O, is the temperature of maximum (or turnover) frequency, f_O. The nominal frequency at any case temperature, T_C, may be calculated from: f = f_O [1 FTC (T_O -T_C)²]. Typically oscillator T_O is approximately equal to the specified resonator T_O.
- 9. This equivalent RLC model approximates resonator performance near the resonant frequency and is provided for reference only. The capacitance C_0 is the static (nonmotional) capacitance between the two terminals measured at low frequency (10 MHz) with a capacitance meter. The measurement includes parasitic capacitance with "NC" pads unconnected. Case parasitic capacitance is approximately 0.05 pF. Transducer parallel capacitance can by calculated as: $C_P \approx C_0 0.05$ pF.
- 10. Tape and Reel standard per ANSI / EIA 481.

SAW Resonator

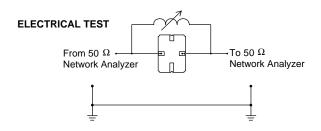
Electrical Connections

The SAW resonator is bidirectional and may be installed with either orientation. The two terminals are interchangeable and unnumbered. The callout NC indicates no internal connection. The NC pads assist with mechanical positioning and stability. External grounding of the NC pads is recommended to help reduce parasitic capacitance in the circuit

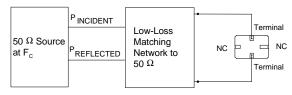


Typical Test Circuit

The test circuit inductor, L_{TEST} , is tuned to resonate with the static capacitance, C_{O} , at F_{C} .



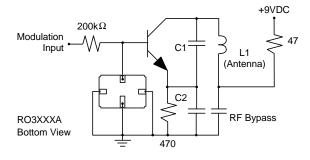
POWER TEST



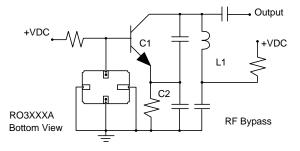
CW RF Power Dissipation = PINCIDENT - P REFLECTED

Typical Application Circuits

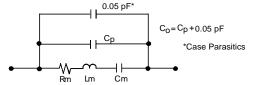
Typical Low-Power Transmitter Application



Typical Local Oscillator Applications

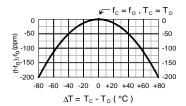


Equivalent LC Model



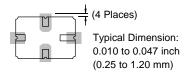
Temperature Characteristics

The curve shown on the right accounts for resonator contribution only and does not include LC component temperature contributions.

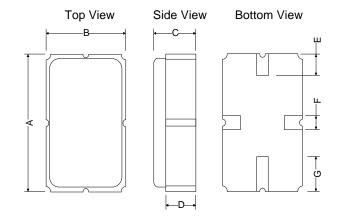


Typical Circuit Board Land Pattern

The circuit board land pattern shown below is one possible design. The optimum land pattern is dependent on the circuit board assembly process which varies by manufacturer. The distance between adjacent land edges should be at a maximum to minimize parasitic capacitance. Trace lengths from terminal lands to other components should be short and wide to minimize parasitic series inductances.



Case Design



	Millimeters			Inches			
Dimensions	wiiiiiiteters			inches			
Dimensions	Min	Nom	Max	Min	Nom	Max	
Α	4.87	5.0	5.13	.191	.196	.201	
В	3.37	3.5	3.63	.132	.137	.142	
С	1.45	1.53	1.60	.057	.060	.062	
D	1.35	1.43	1.50	.040	.057	.059	
Е	.67	.80	.93	.026	.031	.036	
F	.37	.50	.63	.014	.019	.024	
G	1.07	1.20	1.33	.042	.047	.052	

ПОСТАВКА ЭЛЕКТРОННЫХ КОМПОНЕНТОВ

Общество с ограниченной ответственностью «МосЧип» ИНН 7719860671 / КПП 771901001 Адрес: 105318, г.Москва, ул.Щербаковская д.3, офис 1107

Данный компонент на территории Российской Федерации Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

http://moschip.ru/get-element

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г. Москва, ул. Щербаковская д. 3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru moschip.ru_6 moschip.ru 4 moschip.ru 9